

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)				ATTY. DOCKET NO. TCP-004		U.S. APPLICATION NO. 2007566722 Not yet assigned	
				APPLICANT Kenji WATANABE et al			
				FILING DATE herewith		GROUP	
U.S. PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE	
FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation Yes No	
/G.N.R./	2001-72499	03/21/2001	JP			abstract	
/G.N.R./	6-219899	08/09/1994	JP			abstract	
OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)							
/G.N.R./	TANIGUCHI et al; "Spontaneous nucleation of cubic boron nitride single crystal by temperature gradient method under high pressure;" Journal of Crystal Growth, 2001, vol. 222, pages 549-557.						
/G.N.R./	FUKUNAGA et al; "Nucleation and growth of cubic boron nitride using a Ca-B-N solvent"; Diamond and Related Materials, 2004, vol. 13, pages 1709-1713.						
/G.N.R./	AKAMARU et al; "Pressure dependence of the optical-absorption edge of AlN and graphite-type BN"; Journal of Physics and Chemistry of Solids; 2002, vol. 63; pages 887-894.						
/G.N.R./	WATANABE et al; "Direct-bandgap properties and evidence for ultraviolet lasing of hexagonal boron nitride single crystal"; Nature Materials, 2004, vol. 3, No. 6, pages 404-409.						
EXAMINER /G. Nagesh Rao/ (12/25/2008)				DATE CONSIDERED 12/25/2008			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /G.N.B